

Amplifier, Power, 1W 3.5-6.5 GHz

#### **Features**

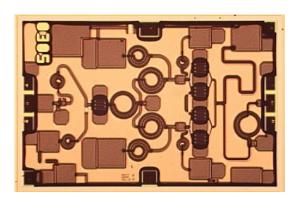
- 1 Watt Saturated Output Power Level
- Variable Drain Voltage (4-10V) Operation
- ♦ MSAG<sup>™</sup> Process

#### Description

The MAAPGM0029-Die is a 2-stage 1 W power amplifier with on-chip bias networks. This product is fully matched to 50 ohms on both the input and output. It can be used as a power amplifier stage or as a driver stage in high power applications.

Fabricated using M/A-COM's repeatable, high performance and highly reliable GaAs Multifunction Self-Aligned Gate (MSAG<sup>TM</sup>) Process, each device is 100% RF tested on wafer to ensure performance compliance.

M/A-COM's MSAG<sup>™</sup> process features robust silicon-like manufacturing processes, planar processing of ion implanted transistors, multiple implant capability enabling power, low-noise, switch and digital FETs on a single chip, and polyimide scratch protection for ease of use with automated manufacturing processes. The use of refractory metals and the absence of platinum in the gate metal formulation prevents hydrogen poisoning when employed in hermetic packaging.



#### **Primary Applications**

- Wireless Local Loop
- 3.7- 4.2 GHz SatCom

| Electrical characteristics. $T_B = 40^{\circ}$ C, $Z_0 = 5052$ , $v_{DD} = 60^{\circ}$ , $v_{GG} = -20^{\circ}$ , $F_{in} = 10^{\circ}$ dBin |                  |         |       |  |  |
|--|------------------|---------|-------|--|--|
| Parameter  | Symbol           | Typical | Units |  |  |
| Bandwidth  | f                | 3.5-6.5 | GHz   |  |  |
| Output Power   | P <sub>OUT</sub> | 31      | dBm   |  |  |
| Power Added Efficiency   | PAE              | 40      | %     |  |  |
| 1-dB Compression Point   | P1dB             | 30      | dBm   |  |  |
| Small Signal Gain  | G                | 20      | dB    |  |  |
| Input VSWR   | VSWR             | 1.5:1   |       |  |  |
| Gate Current   | l <sub>GG</sub>  | < 4     | mA    |  |  |
| Drain Current  | I <sub>DD</sub>  | < 400   | mA    |  |  |
| Output Third Order Intercept   | ΟΤΟΙ             | 42      | dBm   |  |  |
| Noise Figure   | NF               | 7       | dB    |  |  |
| 2 <sup>nd</sup> Harmonic   | 2f               | -15     | dBc   |  |  |
| 3 <sup>rd</sup> Harmonic   | Зf               | -25     | dBc   |  |  |

#### Electrical Characteristics: $T_B = 40^{\circ}C^1$ , $Z_0 = 50\Omega$ , $V_{DD} = 8V$ , $V_{GG} = -2V$ , $P_{in} = 16 \text{ dBm}$

#### 1. T<sub>B</sub> = MMIC Base Temperature

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MAAPGM0029-DIE

Preliminary Information

903240 -

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## Maximum Operating Conditions<sup>2</sup>

| Parameter                             | Symbol            | Absolute Maximum | Units |
|---------------------------------------|-------------------|------------------|-------|
| Input Power                           | P <sub>IN</sub>   | 21.0             | dBm   |
| Drain Supply Voltage                  | V <sub>DD</sub>   | +12.0            | V     |
| Gate Supply Voltage                   | V <sub>GG</sub>   | -3.0             | V     |
| Quiescent Drain Current (No RF)       | I <sub>DQ</sub>   | 470              | mA    |
| Quiescent DC Power Dissipated (No RF) | P <sub>DISS</sub> | 3.1              | W     |
| Junction Temperature                  | Tj                | 180              | °C    |
| Storage Temperature                   | T <sub>STG</sub>  | -55 to +150      | °C    |

2. Operation outside of these ranges may reduce product reliability. Operation at other than the typical values may result in performance outside the guaranteed limits.

#### **Recommended Operating Conditions**

| Characteristic        | Symbol          | Min  | Тур  | Мах    | Unit |
|-----------------------|-----------------|------|------|--------|------|
| Drain Voltage         | V <sub>DD</sub> | 4.0  | 8.0  | 10.0   | V    |
| Gate Voltage          | $V_{GG}$        | -2.3 | -2.0 | -1.5   | V    |
| Input Power           | P <sub>IN</sub> |      | 16.0 | 19.0   | dBm  |
| Junction Temperature  | Tj              |      |      | 150    | °C   |
| MMIC Base Temperature | Τ <sub>B</sub>  |      |      | Note 2 | °C   |

2. Maximum MMIC Base Temperature = 150°C- 25.5 °C/W \* V<sub>DD</sub> \* I<sub>DQ</sub>

#### **Operating Instructions**

This device is static sensitive. Please handle with care. To operate the device, follow these steps.

- 1. Apply  $V_{GG} = -2 V$ ,  $V_{DD} = 0 V$ .
- 2. Ramp V<sub>DD</sub> to desired voltage, typically 8 V.
- 3. Adjust  $V_{GG}$  to set  $I_{DQ}$ , (approximately @ -2 V).
- 4. Set RF input.
- 5. Power down sequence in reverse. Turn gate voltage off last.



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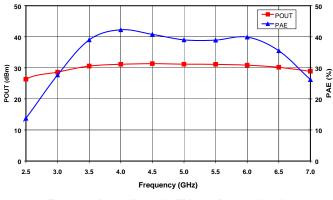


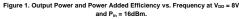
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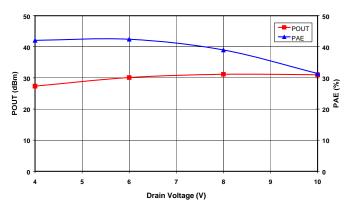


Figure 2. Saturated Output Power and Power Added Efficiency vs. Drain Voltage at fo = 5 GHz.

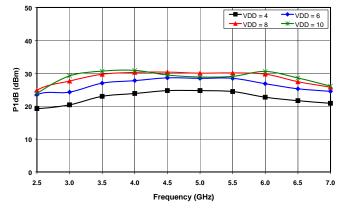


Figure 3. 1dB Compression Point vs. Drain Voltage

30 GAIN -VSWR 25 5 20 Gain (dB) VSWR 15 10 2 5 . 1 3.0 5.0 6.5 7.0 2.5 3.5 4.0 4.5 5.5 6.0 Frequency (GHz)

Figure 4. Small Signal Gain and Input VSWR vs. Frequency at V<sub>DD</sub> = 8V.

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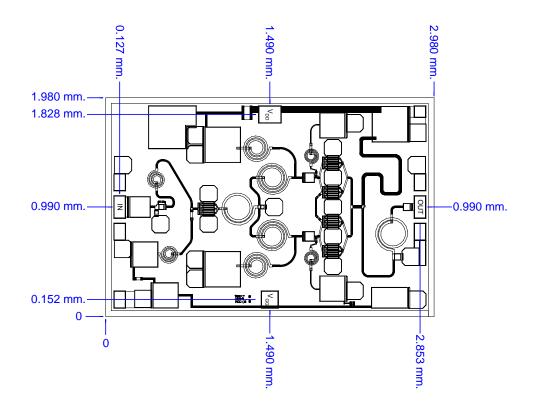


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MAAPGM0029-DIE **Preliminary Information** 

## **Mechanical Information**

Chip Size: 2.980 x 1.980 x 0.075 mm (117x 78 x 3 mils)





Chip edge to bond pad dimensions are shown to the center of the bond pad.

### **Bond Pad Dimensions**

| Pad                         | Size (μm) | Size (mils) |
|-----------------------------|-----------|-------------|
| RF In and Out               | 100 x 200 | 4 x 8       |
| DC Drain Supply Voltage VDD | 200 x 150 | 8 x 6       |
| DC Gate Supply Voltage VGG  | 150 x 150 | 6 x 6       |

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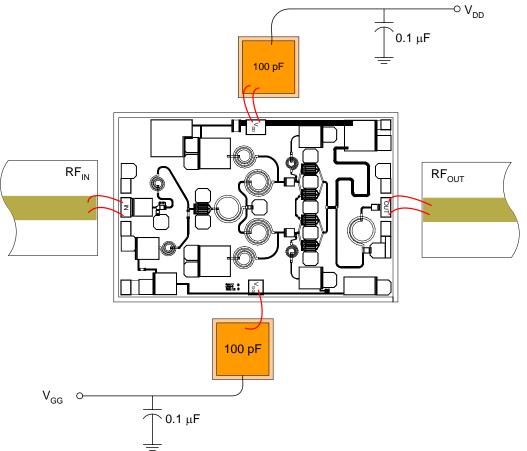


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#### **Assembly and Bonding Diagram**



**Figure 6. Recommended bonding diagram** for pedestal mount. Support circuitry typical of MMIC characterization fixture for CW test-

#### **Assembly Instructions:**

Die attach: Use AuSn (80/20) 1 mil preform solder. Limit time @ 300 °C to less than 5 minutes.

**Wirebonding:** Bond @ 160 °C using standard ball or thermal compression wedge bond techniques. For DC pad connections, use either ball or wedge bonds. For best RF performance, use wedge bonds of shortest length, although ball bonds are also acceptable.

Biasing Note: Must apply negative bias to  $V_{GG}$  before applying positive bias to  $V_{\text{DD}}$  to prevent damage to amplifier.

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